

Absolute spin valve effect

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We study charge transport in a two dimensional hybrid systems consisting of nonmagnetic two dimensional electron gas with spin-orbit interaction sandwiched between a Ferromagnetic lead and a normal metallic lead (FM/2DEG/NM). An *absolute spin valve effect* is shown to exist. It is shown that the conductance of such a hybrid system changes upon rotating the magnetization such that it always stays perpendicular to the current direction. An ASVC (*Absolute Spin Valve Coefficient*) is defined to quantify this effect and its dependence on various parameter is studied.

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In the past two decades the electronic transport properties of magnetic layered structures have received considerable attention from the scientific community. These structures which incorporate ultra thin films have shown a wealth of new effects related to the polarization of conduction electrons such as *giant magnetoresistance* or *spin valve effect* [1]. GMR or spin valve effect is observed in sandwich structures consisting of a Non-magnetic material sandwiched between two ferromagnetic layers (F/NM/F) [2]. The resistance or conductance of such a two terminal device depends on the relative orientation of the magnetization of ferromagnetic layers. Hence to observe these effects one needs a minimum of two magnetic contact whose magnetization orientation can be rotated with respect to each other.

In contrast, here we report an **absolute spin valve effect** which occurs with only one magnetic contact but in presence of spin-orbit interaction. A necessary ingredient for this effect to occur is the simultaneous presence of *exchange* and *spin-orbit* interaction. In particular we study a two dimensional hybrid systems shown in Fig. 1, which consist of a non-magnetic material with spin-orbit interaction sandwiched between a ferromagnetic lead and a normal non-magnetic lead (F/NM/N). The plane of Fig. 1 is xy plane, current is flowing along x axis and the interface is parallel to y axis as depicted in Fig. 1 and the z axis is perpendicular to the plane xy . In this natural coordinate system the magnetization direction is given by usual spherical angle θ and ϕ . Our numerical simulation shows that the resistance or conductance of this F/NM/N hybrid structure depends on the *absolute direction* of magnetization in the coordinate system shown in fig. 1. Specifically we show that the conductance changes when magnetization direction is rotated in yz plane while current is flowing along x axis. In terms of polar coordinates it corresponds to a situation where we keep the azimuthal angle $\phi=90^\circ$ fixed while we change the angle θ . Notice that in this geometry the current direction (x axis) always stays perpendicular to the magnetization direction which lies in the yz plane. We would like to stress that this effect is different from the usual spin valve effect which occurs with two magnetic contacts and corresponds to a change in resistance as the relative

angle between two magnetization direction is changed [5], [6]. While in the effect discussed in present study occurs with only one ferromagnetic contact and corresponds to a dependence of resistance on the absolute direction of magnetization. Which we name aptly as **Absolute spin valve effect**. Also the effect discussed is different from the usual anisotropic magnetoresistance effect which is a change in resistance when magnetization is rotated from being parallel to current direction to the perpendicular [3]. For the geometry shown in Fig. 1 this would correspond to a situation where $\phi=0$ degree is kept fixed while θ is being changed, *i.e.*, magnetization direction rotates in zx plane. In our case magnetization always stays perpendicular to the current. To the best of our knowledge the effect discussed here in this paper has not been discussed in the available literature.

In our recent study for the case when both the contacts are ferromagnetic [7] (FM/2DEG/FM) we pointed out the anisotropy in charge and spin transport. This effect has already been observed experimentally by young *et. al.* [8]. However the systems considered in this paper where only one ferromagnetic contact is present is controversial. Infact in Ref. [9] and [10] it was claimed that conductance for a FM/2DEG/NM systems does not depend on the magnetization direction. However the calculation of Ref. [9] and [10] was for one channel case and also the multiple reflection effect was neglected. In contrast to these claims we show here that conductance of such a system depends on *absolute direction* of magnetization, which we aptly name as **Absolute Spin Valve Effect**. Further the present study is not constrained to a particular kind of spin-orbit interaction which was the case in Ref. [9] and [10]. Also our calculation is exact and takes the quantum effects at single particle level into account [11], [12].

The Hamiltonian of the full system sketched in Fig. 1 is,

$$H = \frac{\hat{p}^2}{2m^*} + V(\mathbf{r}) + \frac{\Delta}{2}\vec{\mu}(\mathbf{r}) \cdot \vec{\sigma} + H_{so} \quad (1)$$

where the first two terms are usual kinetic and potential energies while the third and forth terms represent exchange and spin-orbit interaction, respectively, m^* is the

effective mass of electron, Δ the exchange splitting ($\Delta=0$ for non-magnetic part of the structure), $\vec{\mu}$ a unit vector in the direction of magnetization of FMs and is given by $(\cos\phi\sin\theta, \sin\phi\sin\theta, \cos\theta)$ and σ is a vector of Pauli matrices. H_{so} corresponds to the spin-orbit interaction terms present in the middle region. For our present study we consider two type of spin-orbit interaction: (a) impurity induced spin-orbit interaction causing spin flips during the momentum scattering leading to spin-relaxation mechanism know as Elliot-Yafet spin relaxation [13] (We will denote this kind of interaction as Elliot-Yafet spin orbit interaction (EYSO)). (b) Rashba spin-orbit interaction (RSO) which arises due to asymmetry of confining potential [14].

Elliot-Yafet spin-orbit interaction arises due to the presence of impurities and is given by for the geometry shown in fig. 1,

$$H_{so-ey} = \alpha_{ey}\sigma_z(p_y\partial_x V - p_x\partial_y V) \quad (2)$$

where $V(\mathbf{r})$ is potential due to impurities, p_x and p_y are momentum along x and y direction respectively and α_{ey} is spin-orbit coupling coefficient. For strictly two dimensional systems considered here $V(\mathbf{r})$ depends on x and y coordinates only. We note here that the in strictly two dimensional case the spin-orbit interaction given by eq.(2) commutes with σ_z hence z component of the spin is a good quantum number.

Rashba spin-orbit interaction which arises due to structural asymmetry and has the form,

$$H_{so-ra} = \frac{\alpha_{ra}}{\hbar}(\sigma_x p_y - \sigma_y p_x) \quad (3)$$

where α_{ra} is Rashba spin-orbit coupling coefficient. The strength of Rashba spin-orbit interaction can be controlled by an externally applied gate voltage [15], which led Datta and Das to propose the well know spin transistor [16].

The essential difference between EYSO (eq.(2)) and RSO (eq.(3)) can be realized if we look at spin diffusion length for the two cases. The spin diffusion lengths l_{sd-ey} and l_{sd-ra} for EYSO and RSO respectively, is given by

$$l_{sd-ey} = \frac{l_{el}}{\sqrt{2}\hbar\alpha_{ey}k_f^2} \quad (4)$$

$$l_{sd-ra} = \frac{\hbar^2\pi}{2m^*\alpha_{ra}} \quad (5)$$

where l_{el} is elastic mean free path, k_f is Fermi momentum and m^* is effective mass. We see that l_{sd-ey} depends on the mean free path which is due to the fact that the strength of EYSO given by (eq.(2)) is determined by the impurities while l_{sd-ra} is independent of mean free path since the strength of RSO is essentially controlled by structural asymmetry [15].

For numerical calculation we discretize the system sketched in fig. 1 on a square lattice of lattice constant

a with N_x sites along x axis and N_y sites along y axis. The length and width of the systems is $L = N_x a$ and $W = N_y a$ respectively. Accordingly we use corresponding tight binding version of the Hamiltonians introduced in eq. (1), (2) and (3). In the tight binding version kinetic energy term in eq. (1) transforms into the hopping term t and the potential energy term $V(\mathbf{r})$ and exchange coupling Δ give rise to the on-site energy term ϵ_i . Model parameters in tight binding model are, hopping matrix element $t \equiv (\hbar^2/2m^*a^2)$ lattice spacing a and on-site energy ϵ . Impurities are modeled as Anderson disorder such that on-site energies ϵ are distributed randomly between $-V/2$ and $+V/2$, where V characterizes the strength of disorder. Mean free path for two dimensional tight binding model is given as $l_{el} = \frac{96\sqrt{E_f}ta}{\pi V^2}$, where t and a are hopping parameter and lattice spacing respectively [11], [12]. The spin diffusion lengths defined in eq.(4) and eq.(5) can be recast in terms of tight binding model parameter and are given as $l_{sd}^{ey} = \frac{l_{el}t}{\sqrt{2}\lambda_{ey}E_f}$ and $l_{sd}^{ra} = \frac{\pi a}{\lambda_{ra}}$, where $\lambda_{ey} = \hbar\alpha_{ey}/a^2$ and $\lambda_{ra} = \alpha_{ey}/2ta$ are dimensionless EYSO coupling parameter and RSO coupling parameter respectively. For details of tight binding form of Hamiltonian we refer the reader to references [7], [11], [12].

The conductance and spin resolved conductances are calculated using Landauer-Büttiker [17] formalism with the help of non-equilibrium Green's function formalism [12]. The two terminal spin resolved conductance (for a given spin quantization axis) is given by [11] [12]

$$G^{\sigma\sigma'}(\epsilon_F) = \frac{e^2}{h} Tr[\Gamma_1^\sigma G_{1N_x}^{\sigma\sigma'+} \Gamma_{N_x}^{\sigma'} G_{N_x1}^{\sigma'\sigma-}] \quad (6)$$

where $\Gamma_{1(N_x)}$ self-energy function for the isolated ideal leads and are given by $\Gamma_{p(q)} = t^2 A_{p(q)}$, where $A_{p(q)}$ is the spectral density in the respective lead when it is decoupled from the structure, $G_{1N_x}^{\sigma\sigma'+}$ and $G_{N_x1}^{\sigma'\sigma-}$ are the retarded and advanced Green's functions of whole structure taking leads into account. The trace is over spatial degrees of freedom. The total conductance is sum of spin-conserved conductance and spin-flip conductance, i.e., $G = G_{sc} + G_{sf}$ where the spin-conserved and spin-flip conductance are $G_{sc} = G^{\uparrow\uparrow} + G^{\downarrow\downarrow}$ and $G_{sf} = G^{\uparrow\downarrow} + G^{\downarrow\uparrow}$ respectively.

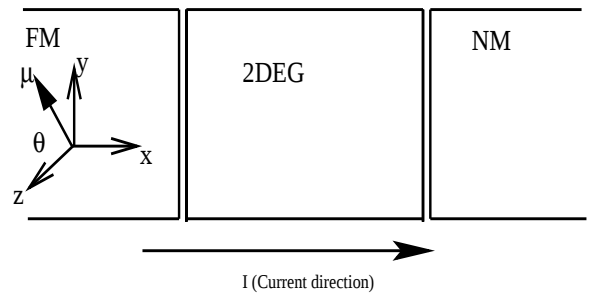


FIG. 1. A 2DEG connected to a Ferromagnetic and non-magnetic ideal leads. 2DEG lies in xy plane as shown in fig. Magnetization direction ($\vec{\mu}$) of ferromagnetic lead is rotated in yz plane while current is flowing along x direction as depicted above.

We first present numerical results which shows the *Absolute spin valve effect* clearly. For numerical simulation we have taken $N_x = N_y = 50$. Fermi energy and exchange splitting is kept fixed at $E_F/t = 1.0$, and $\Delta/t = 0.5$, where t is the usual hopping parameter in the tight binding model.

In fig. 2 and fig. 3 total conductance, spin conserved conductance and spin flip conductance are shown as a function of angle θ while $\phi = 90$ is kept fixed. Fig. 2 present results for RSO interaction, i.e., $\lambda_{ra}=0.1$, and $\lambda_{ey}=0$. Fig. 3 present results for EYSO interaction, i.e., $\lambda_{ra}=0$, and $\lambda_{ey}=0.1$. The strength of disorder potential is chosen $V/t=1$, corresponding to a mean free path of $l_{el} = 30a$. We see that conductance changes as magnetization is rotated from z axis to y axis. We remind the reader that we do not consider simultaneous presence of EYSO and RSO, rather we consider the situation where either of the two spin-orbit interactions are non zero.

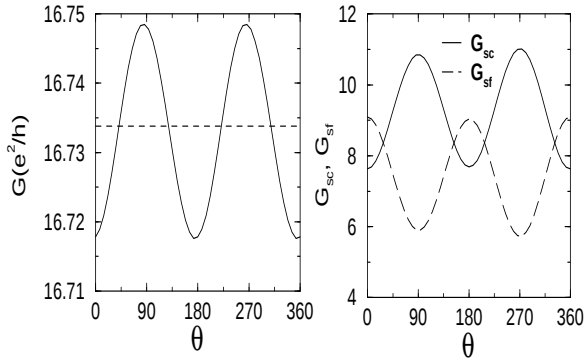


FIG. 2. Conductance, spin conserved and spin flip conductance as a function of polar angle θ for RSO interaction. The parameter are $\lambda_{so-ra}/t = 0.1$ (spin diffusion length $l_{sd-ra} = 31a$), $E_f/t = 1.0$, $V/t = 1.0$ and exchange splitting in FM is $\Delta/t = 0.5$.

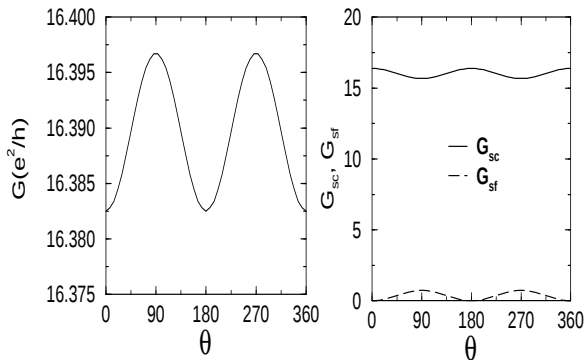


FIG. 3. Total conductance and spin conserved and spin flip conductance as a function of polar angle θ for EYSO interaction. The parameter are $\lambda_{so-ey}/t = 0.1$ (spin diffusion length $l_{sd-ey} = 300a$), $E_f/t = 1.0$, $W/t = 1.0$ and exchange splitting in FM is $\Delta/t = 0.5$.

To be specific, when $\theta=0$, magnetization is parallel to z axis, while for $\theta = 90$ magnetization is parallel to y axis. We would like to stress that the current is flowing along x axis, hence the magnetization which is being rotated in yz plane is always perpendicular to the current direction. Hence effect presented here is qualitatively new effect and is different from the usual spin valve effect and anisotropic magnetoresistance as pointed out in introduction. We see that the effect is present for both kind of spin-orbit coupling though the order of magnitude is different. This can be understood if we examine the spin conserved and spin flip conductances shown in right panels of the fig. 2 and fig. 3. As is seen the magnitude of spin conserved and spin flip conductance are comparable for RSO interaction (fig. 2 right panel) while for EYSO interaction spin flip conductance is much smaller than the spin conserved conductances. This is so because the spin diffusion length for EYSO is $l_{sd}^{ey} = 10l_{el} = 300a$ while for RSO it is $l_{sd}^{ra} = 31a$, which is ten times smaller than l_{sd}^{ey} . Hence the magnitude of effect is directly determined by the spin diffusion length. This is also confirmed by switching off the spin-orbit interaction, i.e., by taking $\lambda_{ey} = \lambda_{ra}=0$, in which case conductance shows no variation with angle θ as shown in fig. 2 (the dashed straight line in left panel). Further we would like to point out that for EYSO the spin flip conductance goes to zero for $\theta=0$ which is consistent with the fact that z component of spin is conserved for EYSO in strictly two dimensional case.

Having demonstrated absolute spin valve effect. We now proceed to quantify this effect. To this end we define, in analogy with the other magnetoresistance effect, a *Absolute Spin Valve Coefficient* as.

$$ASVC = 2 \frac{(G(\vec{\mu} \parallel \mathbf{z}) - G(\vec{\mu} \parallel \mathbf{y}))}{(G(\vec{\mu} \parallel \mathbf{z}) + G(\vec{\mu} \parallel \mathbf{y}))}. \quad (7)$$

Note the ASVC coefficient defined above differs from the standard definition in the normalization. This definition always give ASVC between 1 and -1. The ASVC coefficient defined above measures the change in conductance normalized to the average conductance. Since a non zero value of ASVC requires simultaneous presence of exchange and spin-orbit interaction, it is natural to study ASVC as function of spin-orbit interaction. As we have already seen that the effect is essentially determined by spin-diffusion lengths hence we plot in Fig. 4, ASVC as a function of spin diffusion lengths which are inversely proportional to spin-orbit coupling. This is also motivated by the fact that RSO coupling can be externally controlled by gate voltage [15]. Left panel in fig. 4 corresponds to case where only RSO coupling is present and the Right panel is for only EYSO interaction. The other

parameter are $W/t = 1$ and $E_f/t = 1$ and exchange splitting in FM is $\Delta/t = 0.5$. For Fig. 4 disorder averaging was done for 15 different configuration. We see that for weak spin-orbit interaction ASVC shows quadratic behavior for both RSO and EYSO interaction and is always negative. The magnitude of effect is of 0.1% since the spin diffusion lengths are large compared to the systems size, which is 50×50 . However since the RSO coupling can be controlled by external gate voltage and relatively large, it is desirable to see how ASVC changes for large values of RSO coupling strength. This is shown in Fig. 5, where we have varied RSO coupling strength λ_{ra} over a range such that the corresponding spin diffusion length becomes smaller than the system size. We see the ASVC coefficient increases linearly with decreasing spin-diffusion length and can reach values of the order of 1%.

In summary we have predicted an new absolute spin valve effect in two dimensional heterostructure with one ferromagnetic contact. The effect exist due to simultaneous presence of exchange and spin-orbit interaction and is closely related to breaking of SU(2) symmetry in spin space due to the presence of spin-orbit interaction. This is supported by numerical calculation where the said effect is shown to exist for two different kind of spin-orbit interaction. The ASVC is of the order of 1%, which is encouraging. Since the usual AMR of this magnitude has been experimentally measured [1]. In light of this we hope the predicted effect should be observable and may lead to new spin valve devices.

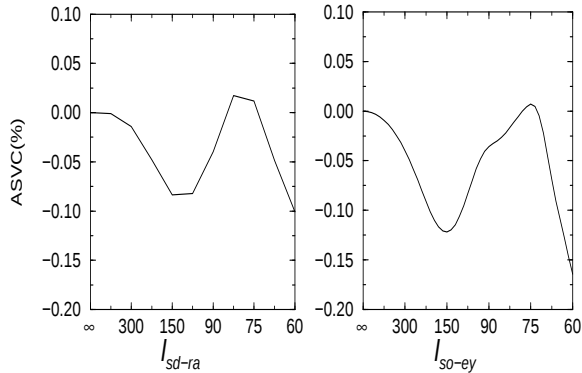


FIG. 4. ASVC coefficient (defined in eq.(7)) as a function of spin diffusion length. Left panel corresponds to RSO interaction and right panel is for EYSO interaction. The other parameters are same as in fig. 2 and Fig. 3.

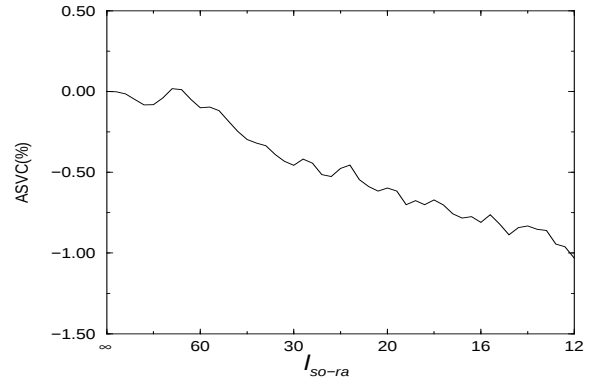


FIG. 5. ASVC coefficient (defined in eq.(7)) as a function of spin diffusion length for RSO interaction. The other parameters are same as for Fig. 4.

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